# onsemi

### TinyLogic HS Unbuffered Inverter

## NC7SU04

#### Description

The NC7SU04 is a single special purpose CMOS Inverter. The inverter circuit is designed with a single unbuffered stage to facilitate use in crystal oscillator applications. It is not intended for use in logic inversion applications.

Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad  $V_{CC}$  range. ESD protection diodes inherently guard both input and output with respect to the  $V_{CC}$  and GND rails.

#### Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPak<sup>TM</sup> Leadless Package
- Unbuffered for Crystal Oscillator Applications
- Low Quiescent Power:  $I_{CC} < 1 \mu A$
- Balanced Output Drive: 2 mA I<sub>OL</sub>, -2 mA I<sub>OH</sub>
- Broad V<sub>CC</sub> Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

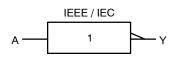


Figure 1. Logic Symbol

	SIP6 CASE 127EB Pin 1-	E5KK XYZ
THE REAL	SC-74A CASE 318BQ	7SU4M• 0 •
CEEL	SOT23–5 CASE 527AH	
	SC-88A CASE 419A-02	SU4M• o •
E5, 7SU4, SU KK XY Z M	4 = Specific Device C = 2-Digit Lot Run T = 2-Digit Date Cod = Assembly Plant C = Data Code* = Pb-Free Package	raceability Code e Format Code

(Note: Microdot may be in either location)

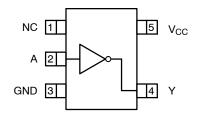
\*Date Code orientation and/or position may vary depending upon manufacturing location.

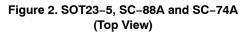
#### ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

MARKING DIAGRAMS

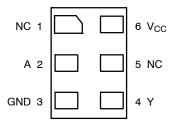
#### **Pin Configurations**





#### **PIN DESCRIPTIONS**

Pin Name	Description
А	Input
Y	Output
NC	No Connect



#### Figure 3. MicroPak (Top Through View)

#### **FUNCTION TABLE** $(Y = \overline{A})$

Inputs	Output
А	Y
L	Н
Н	L

H = HIGH Logic Level L = LOW Logic Level

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Paran	neter	Min	Max	Unit	
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V	
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-20	mA	
		$V_{IN} > V_{CC}$	-	+20		
V <sub>IN</sub>	DC Input Voltage	•	-0.5	V <sub>CC</sub> + 0.5	V	
Ι <sub>ΟΚ</sub>	DC Output Diode Current	V <sub>OUT</sub> < 0 V	-	-20	mA	
	V <sub>OUT</sub> > V <sub>CC</sub>		-	+20		
V <sub>OUT</sub>	DC Output Voltage		-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>OUT</sub>	DC Output Source or Sink Curre	nt	-	±12.5	mA	
$I_{CC} \text{ or } I_{GND}$	DC V <sub>CC</sub> or Ground Current per Output Pin		-	±25	mA	
T <sub>STG</sub>	Storage Temperature		-65	+150	°C	
Τ <sub>J</sub>	Junction Temperature		-	+150	°C	
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C	
PD	Power Dissipation in Still Air	SC-74A / SOT23-5	-	390	mW	
		SC-88A	-	332	7	
		MicroPak-6	_	812	1	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### NC7SU04

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		2.0	6.0	V
V <sub>IN</sub>	Input Voltage		0	V <sub>CC</sub>	V
V <sub>OUT</sub>	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
$\theta_{JA}$	Thermal Resistance	SC-74A / SOT23-5	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

#### DC ELECTICAL CHARACTERISTICS

				-	T <sub>A</sub> = +25°C	;	T <sub>A</sub> = −40 to +85°C		
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	HIGH Level Input Voltage	2.0 3.0 4.5 6.0		1.70 2.45 3.60 4.80	- - - -	- - - -	1.70 2.45 3.60 4.80	- - - -	V
V <sub>IL</sub>	LOW Level Input Voltage	2.0 3.0 4.5 6.0		- - - -	- - - -	0.30 0.50 0.90 1.20	- - - -	0.30 0.50 0.90 1.20	V
V <sub>OH</sub>	HIGH Level Output Voltage	2.0 3.0 4.5 6.0		1.80 2.50 4.00 5.50	2.0 3.0 4.5 5.9	- - - -	1.80 2.50 4.00 5.50	- - - -	V
		3.0 4.5 6.0	$V_{IN} = GND$ $I_{OH} = -1.3 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	2.68 4.18 5.68	2.82 4.33 5.76	- - -	2.63 4.13 5.63	- - -	V
V <sub>OL</sub>	LOW Level Output Voltage	2.0 3.0 4.5 6.0		- - - -	0.00 0.00 0.01 0.04	0.20 0.50 0.50 0.50	- - - -	0.20 0.50 0.50 0.50	V
		3.0 4.5 6.0	$V_{IN} = V_{CC}$ $I_{OL} = 1.3 \text{ mA}$ $I_{OL} = 2.0 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$	- - -	0.11 0.12 0.15	0.26 0.26 0.26	- - -	0.33 0.33 0.33	V
I <sub>IN</sub>	Input Leakage Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	±0.1	-	±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>IN</sub> = V <sub>CC</sub> , GND	-	-	1.0	-	10.0	μA

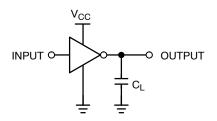
#### NC7SU04

#### AC ELECTRICAL CHARACTERISTICS

					Γ <sub>A</sub> = +25°C	;	T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay (Figure 4, 6)	5.0	C <sub>L</sub> = 15 pF	-	3	15	-	-	ns
<sup>t</sup> PHL		2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF	- - -	17 9 7 6.5	100 27 20 17	- - - -	125 35 25 21	ns
t <sub>TLH</sub> ,	Output Transition Time	5.0	C <sub>L</sub> = 15 pF	-	4	10	-	-	ns
t <sub>THL</sub>	(Figure 4, 6)	2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF	- - - -	25 16 12 10	125 35 25 21	- - - -	155 45 31 26	ns
C <sub>IN</sub>	Input Capacitance	Open		-	2	10	-	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	-	4	-	_	-	pF

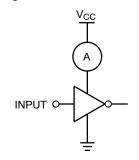
2.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle.  $C_{PD}$  is related to I<sub>CCD</sub> dynamic operating current by the expression: I<sub>CCD</sub> = ( $C_{PD}$ ) (V<sub>CC</sub>) ( $f_{IN}$ ) + (I<sub>CC</sub>static).

#### AC Loading and Waveforms

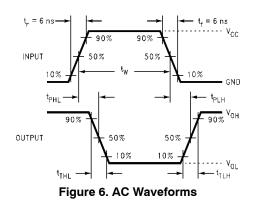


 $C_L$  includes load and stray capacitance Input PRR = 1.0 MHz;  $t_W$  = 500 ns

#### Figure 4. AC Test Circuit



Input = AC Waveform; PRR = Variable; Duty Cycle = 50%. Figure 5. I<sub>CCD</sub> Test Circuit





### NC7SU04

#### **ORDERING INFORMATION**

Order Number	Top Mark	Package Description	Shipping <sup>†</sup>
NC7SU04M5X	7SU4	SC-74A	3000 / Tape & Reel
NC7SU04M5X-L22090	7SU4	SOT23-5	3000 / Tape & Reel
NC7SU04P5X	SU4	SC-88A	3000 / Tape & Reel
NC7SU04P5X-L22057	SU4	SC-88A	3000 / Tape & Reel
NC7SU04L6X	E5	SIP6, MicroPak	5000 / Tape & Reel
NC7SU04L6X-L22175	E5	SIP6, MicroPak	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

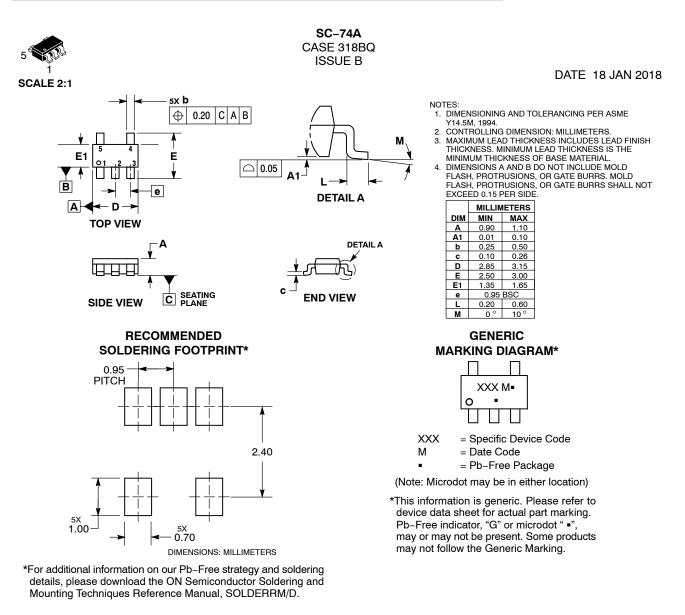


SIP6 1.45X1.0 CASE 127EB ISSUE O

DATE 31 AUG 2016







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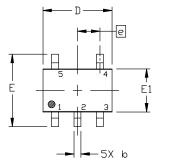
#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

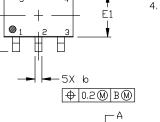
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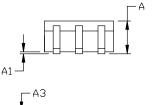
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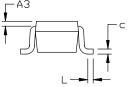
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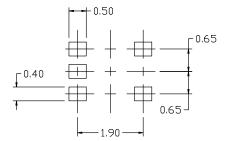
DATE 11 APR 2023











#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN,	NDM.	MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e		0.65 BSI	С		
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

#### **GENERIC MARKING**





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
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